Vishay Polytech

vPolyTan[™] Polymer Surface Mount Chip Capacitors, Molded Case, Hi-Rel COTS



LINKS TO ADDITIONAL RESOURCES



PERFORMANCE / ELECTRICAL CHARACTERISTICS

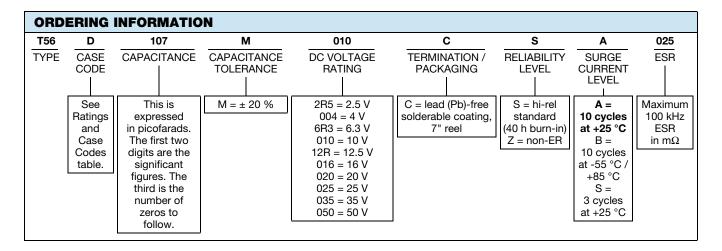
Operating Temperature: -55 °C to +105 °C / 125 °C Capacitance Range: 10 μ F to 680 μ F Capacitance Tolerance: \pm 20 % Voltage Rating: 2.5 V_{DC} to 50 V_{DC}

FEATURES

- Ultra low ESR
- High reliability processing including:
 - 100 % surge current tested
 - Accelerated voltage conditioning
 - Thermal shock
 - Statistical DC leakage screening at elevated temperature and voltage, covered by U.S. patent and worldwide patents pending.
 PATENT(S): <u>www.vishay.com/patents/</u>
- High ripple current capability
- Stable capacitance over operating temperature, voltage, and frequency range
- No wear out effect
- Terminations: Ni / Pd / Au
- Compatible with "high volume" automatic pick and place equipment
- Moisture sensitivity level 3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Decoupling, smoothing, filtering
- Switch mode and point of load power supply
- Infrastructure equipment
- Storage and networking



PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.

Revision: 13-Dec-2023	1	Document Number: 40219	
F	For technical questions, contact: polytech@vishay.com		
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ROHS COMPLIANT

HALOGEN

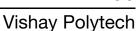
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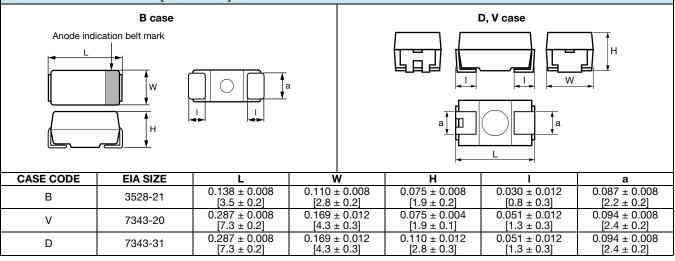
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DIMENSIONS in inches [millimeters]

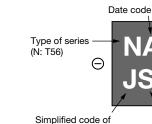
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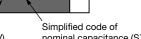


RATINGS AN	RATINGS AND CASE CODES								
μF	2.5 V	4.0 V	6.3 V	10 V	16 V	20 V	25 V	35 V	50 V
10								D/B	D
15						B/V	B/V	V	
22					В	V	V	D	
33			В	В	D/V	V	D/V		
47	В	В	В	B	D/V				
68	В	В		V	V				
100			V	D/V	D/V		D		
150		V	D/V	D/V					
220	V	D/V	D/V	D/V					
330	V	D/V	D/V	D					
470	V								
680			D						

MARKING



Anode indication belt mark



Simplified code of	
rated voltage (J: 6.3 V)	

nominal capacitance (S7: 47 µF)

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VOLTAG	E CODE	CAPACITANCE CODE		
V	CODE	CAP, µF	CODE	
2.5	e	10	A7	
4	G	15	E7	
6.3	J	22	J7	
10	A	33	N7	
16	С	47	S7	
20	D	68	W7	
25	E	100	A8	
35	V	150	E8	
50	Н	220	J8	
		330	N8	
		470	S8	
		680	W8	

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For technical questions, contact: polytech@vishay.com

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DATE	CODE											
YEAR		MONTH										
TEAN	1	2	3	4	5	6	7	8	9	10	11	12
2017	А	В	С	D	E	F	G	Н	J	K	L	М
2018	Ν	Р	Q	R	S	Т	U	V	W	Х	Y	Z
2019	а	b	с	d	е	f	g	h	j	k	I	m
2020	n	р	q	r	s	t	u	v	w	х	У	z
2021	А	В	С	D	E	F	G	Н	J	K	L	М
2022	Ν	Р	Q	R	S	Т	U	V	W	Х	Y	Z
2023	а	b	с	d	е	f	g	h	j	k	I	m
2024	n	р	q	r	S	t	u	v	w	х	у	Z

Note

• Marking code repeats every four years in alphabetical order (letter of I, i, O, and o are excluded)

CAPACITANCE (µF)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (µA)	MAX. DF AT 25 °C 120 Hz (%)	MAX. ESR AT + 25 °C 100 kHz (mΩ)	MAX. RIPPLE AT 45 °C 100 kHz I _{RMS} (A)	MAX. OPERATING TEMPERATURE (°C)	85 °C / 85 %, R. V., 500 h CAPABLE
		2.5	V _{DC} AT +105	5 °C; 1.7 V _D	_C AT +125 °C	;		
47	В	T56B476M2R5C(1)(2)070	11.7	8	70	1.36	105	
68	В	T56B686M2R5C(1)(2)070	17.0	8	70	1.36	105	
220	V	T56V227M2R5C(1)(2)025	55.0	10	25	2.73	105	
330	V	T56V337M2R5C(1)(2)025	82.5	10	25	2.73	105	
470	V	T56V477M2R5C(1)(2)025	117.5	10	25	2.73	105	
		4	V _{DC} AT +105	°C; 2.7 V _{DC}	AT +125 °C			
47	В	T56B476M004C(1)(2)070	18.8	8	70	1.36	105	
68	В	T56B686M004C(1)(2)070	27.2	8	70	1.36	105	
150	V	T56V157M004C(1)(2)025	60.0	10	25	2.73	105	
220	D	T56D227M004C(1)(2)025	88.0	10	25	3.00	125	•
220	V	T56V227M004C(1)(2)025	88.0	10	25	2.73	105	
330	D	T56D337M004C(1)(2)025	132.0	10	25	3.00	125	•
330	V	T56V337M004C(1)(2)025	132.0	10	25	2.73	105	
		6.3	V _{DC} AT +105	5 °C; 4.2 V _D	_C AT +125 °C	;		
33	В	T56B336M6R3C(1)(2)070	20.7	8	70	1.36	105	
47	В	T56B476M6R3C(1)(2)070	29.6	8	70	1.36	105	
100	V	T56V107M6R3C(1)(2)045	63.0	10	45	2.03	105	
150	D	T56D157M6R3C(1)(2)025	94.5	10	25	3.00	125	•
150	V	T56V157M6R3C(1)(2)025	94.5	10	25	2.73	105	
220	D	T56D227M6R3C(1)(2)025	138.6	10	25	3.00	125	•
220	V	T56V227M6R3C(1)(2)025	138.6	10	25	2.73	105	
330	D	T56D337M6R3C(1)(2)025	207.9	10	25	3.00	125	•
330	V	T56V337M6R3C(1)(2)025	207.9	10	25	2.73	105	
680	D	T56D687M6R3C(1)(2)025	428.4	10	25	3.00	105	

Note

Part number definitions: (1) Reliability level: Z, S •

(2) Surge current: A, B, S

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(UE) CODE PART NUMBER AT 25 °C 120 Hz 100 kHz	STANDARD	RATI	NGS						
33 B TS6B336M010C(1)(2)070 33.0 8 70 1.36 105 47 B T58b476M10C(1)(2)070 47.0 8 70 1.36 105 68 V T56V668M010C(1)(2)025 100.0 10 25 3.00 105 100 D TS6D107M010C(1)(2)045 100.0 10 45 2.03 105 100 V TS6V107M010C(1)(2)045 150.0 10 25 3.00 105 150 V TS6V157M010C(1)(2)025 150.0 10 25 3.00 105 220 D T56D227M010C(1)(2)025 220.0 10 25 3.00 105 220 V T56D227M010C(1)(2)07 52.2 8 70 1.36 105 330 D T56D337M010C(1)(2)07 52.2 8 70 1.36 105 331 V T56D476M016C(1)(2)070 52.2 10 70 1.63 105 <			PART NUMBER	AT 25 °C	AT 25 °C 120 Hz	AT + 25 °C 100 kHz	AT 45 °C 100 kHz I _{RMS}	OPERATING TEMPERATURE	85 °C / 85 %, R. V., 500 h CAPABLE
47 B T56B476M010C(1)(2)070 47.0 8 70 1.36 105 68 V T56V9686M010C(1)(2)020 68.0 10 60 1.76 105 100 D T56D107M010C(1)(2)025 100.0 10 45 2.03 105 100 V T56V107M010C(1)(2)025 150.0 10 25 3.00 105 150 D T56D157M010C(1)(2)025 150.0 10 25 3.00 105 220 D T56V157M010C(1)(2)025 220.0 10 40 2.37 125 • 220 D T56V227M010C(1)(2)025 220.0 10 40 2.37 125 • 330 D T56V227M010C(1)(2)025 330.0 10 25 3.00 105 221 B T56V227M010C(1)(2)07 52.8 10 70 1.63 105 330 D T56V33M016C(1)(2)070 52.8 10 70 1.63 105 33 V T56V476M016C(1)(2)070 75.2 10 <t< td=""><td></td><td></td><td>10</td><td>V_{DC} AT +105</td><td>5 °C; 6.7 V_D</td><td>c AT +125 °C</td><td></td><td></td><td></td></t<>			10	V _{DC} AT +105	5 °C; 6.7 V _D	c AT +125 °C			
68 V T56V686M010C(1)(2)020 68.0 10 60 1.76 105 100 D T56D107M010C(1)(2)040 10.0 10 45 3.00 105 100 V T56V107M010C(1)(2)045 100.0 10 45 2.03 105 150 D T56D157M010C(1)(2)025 150.0 10 25 3.00 105 220 D T56D127M010C(1)(2)025 150.0 10 25 3.00 105 220 D T56D227M010C(1)(2)025 220.0 10 40 2.37 125 • 220 V T56D227M010C(1)(2)025 230.0 10 25 3.00 105 330 D T56D227M010C(1)(2)025 30.0 10 25 3.00 105 330 D T56D227M010C(1)(2)025 30.0 10 25 3.00 105 331 D T56D27M010C(1)(2)070 52.8 10 70 1.63 105	33	В	T56B336M010C(1)(2)070	33.0	8	70	1.36	105	
100 D T56D107M010C(1)[2]045 100.0 10 40 2.37 125 • 100 D T56D107M010C(1)[2]045 100.0 10 40 2.37 125 • 100 V T56V107M010C(1)[2]025 150.0 10 25 2.03 105 150 V T56D157M010C(1)[2]025 150.0 10 25 2.73 105 220 D T56D227M010C(1)[2]025 220.0 10 40 2.37 125 • 220 V T56D227M010C(1)[2]025 220.0 10 45 2.03 105 220 V T56D237M010C(1)[2]042 220.0 10 25 2.73 105 330 D T56D337M010C(1)[2]042 30.0 10 25 3.00 105 33 D T56B328M016C(1)[2]070 52.8 10 70 1.63 105 33 D T56B476M016C(1)[2]070 75.2 10 70 1.63 105 47 V T56V476M016C(1)[2]070 75.2	47	В	T56B476M010C(1)(2)070	47.0	8	70	1.36	105	
100 D T56D107M010C(1)(2)040 100.0 10 40 2.37 125 • 100 V T56V107M010C(1)(2)025 150.0 10 25 3.00 105 150 D T56D157M010C(1)(2)025 150.0 10 25 3.00 105 220 D T56D227M010C(1)(2)025 220.0 10 40 2.37 125 • 220 D T56D227M010C(1)(2)025 220.0 10 40 2.37 105 220 V T56V227M010C(1)(2)025 330.0 10 25 3.30 105 330 D T56D337M010C(1)(2)025 330.0 10 25 3.30 105 333 V T56D337M010C(1)(2)070 52.8 10 70 1.83 105 47 D T56D476M016C(1)(2)070 75.2 10 70 1.83 105 47 D T56V476M016C(1)(2)070 75.2 10 70 1.83 105 100 D T56V476M016C(1)(2)070 75.2 10	68	V	T56V686M010C(1)(2)060	68.0	10	60	1.76	105	
100 V T56V107M010C(1)(2)025 100.0 10 45 2.03 105 150 D T56D157M010C(1)(2)025 150.0 10 25 2.73 105 220 D T56D227M010C(1)(2)025 220.0 10 25 2.73 105 220 D T56D227M010C(1)(2)025 220.0 10 40 2.37 125 • 220 V T56D227M010C(1)(2)025 220.0 10 40 2.37 105 330 D T56D237M010C(1)(2)025 330.0 10 25 3.00 105 220 V T56D237M010C(1)(2)025 330.0 10 25 3.00 105 330 D T56D337M010C(1)(2)070 52.8 10 70 1.86 105 33 D T56D476M016C(1)(2)070 75.2 10 70 1.63 105 47 D T56D476M016C(1)(2)070 75.2 10 70 1.63 105 100 V T56V17M016C(1)(2)070 75.2 10 70	100	D	T56D107M010C(1)(2)025	100.0	10	25	3.00	105	
150 D T56D157M010C(1)(2)025 150.0 10 25 3.00 105 150 V T56V157M010C(1)(2)025 150.0 10 25 2.73 105 220 D T56D227M010C(1)(2)025 220.0 10 40 2.37 125 • 220 V T56D237M010C(1)(2)025 220.0 10 25 2.73 105 330 D T56D237M010C(1)(2)025 330.0 10 25 2.73 105 220 V T56V237M010C(1)(2)075 35.2 8 70 1.36 105 33 D T56D337M016C(1)(2)070 52.8 10 70 1.63 105 47 D T56V476M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 100 D T56V476M016C(1)(2)070 168.0 10 50 <	100	D	T56D107M010C(1)(2)040	100.0	10	40	2.37	125	•
150 V T56V157M010C(1)(2)025 150.0 10 25 2.73 105 220 D T56D227M010C(1)(2)025 220.0 10 40 2.37 125 • 220 V T56D227M010C(1)(2)025 220.0 10 40 2.37 105 330 D T56D337M010C(1)(2)025 330.0 10 25 3.00 105 T6Woc AT +105 °C; 10.7 Voc AT +125 °C 7 V T56D336M016C(1)(2)070 52.8 10 70 1.79 125 • 33 V T56V36M016C(1)(2)070 52.8 10 70 1.63 105 47 D T56D476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V36M016C(1)(2)070 75.2 10 70 1.63 105 100 V T56V16M016C(1)(2)070 75.2 10 70 1.63 105 110 V T56V16M016C(1)(2)070 75.2 10 70 1.63 105 100	100	V	T56V107M010C(1)(2)045	100.0	10	45	2.03	105	
220 D T56D227M010C(1)(2)025 220.0 10 25 3.00 105 220 V T56D227M010C(1)(2)025 220.0 10 25 3.00 105 330 D T56D327M010C(1)(2)025 220.0 10 25 3.00 105 ISE Vac27M010C(1)(2)025 220.0 10 25 3.00 105 ISE Vac27M010C(1)(2)070 35.2 8 70 1.36 105 ISE Vac27M010C(1)(2)070 35.2 8 70 1.63 105 ISE Vac27M010C(1)(2)070 52.8 10 70 1.63 105 47 D T56V376M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 100 D T56V167M016C(1)(2)070 108.8 10 70 1.63 105 100 D T56V156M020C(1)(2)000 160.0	150	D	T56D157M010C(1)(2)025	150.0	10	25	3.00	105	
220 D T56D227M010C(1)(2)040 220.0 10 40 2.37 125 • 230 V T56V227M010C(1)(2)025 220.0 10 25 3.00 105 330 D T56D237M010C(1)(2)025 330.0 10 25 3.00 105 ISVATINO VALISION VA	150	V	T56V157M010C(1)(2)025	150.0	10	25	2.73	105	
220 V T56V227M010C(1)(2)025 220.0 10 25 2.73 105 330 D T56D337M010C(1)(2)025 330.0 10 25 3.00 105 I6 V _{DC} AT +105 °C; 10.7 V _{DC} AT +125 °C 22 B T56B236M016C(1)(2)070 52.8 10 70 1.79 125 • 33 V T56D336M016C(1)(2)070 52.8 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 100 D T56V476M016C(1)(2)070 75.2 10 70 1.63 105 100 D T56V107M016C(1)(2)050 160.0 10 50 1.13 105 100 V T56V107M016C(1)(2)050 160.0 10 50 1.22 105 15 B T56B156M020C(1)(2)040 44.0 10 40 2.16 105 22 V T56V	220	D	T56D227M010C(1)(2)025	220.0	10	25	3.00	105	
330 D T56D337M010C(1)(2)025 330.0 10 25 3.00 105 I E V _{DC} AT +105 °C; 10.7 V _{DC} AT +125 °C 22 B T56B2260M016C(1)(2)070 35.2 8 70 1.36 105 33 D T56D336M016C(1)(2)070 52.8 10 70 1.79 125 • 47 D T56V36M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V476M016C(1)(2)070 16.8 10 70 1.63 105 100 D T560170M016C(1)(2)050 160.0 10 50 1.2 125 • 100 V T560170M016C(1)(2)050 30.0 8 90 1.2 105 15 B T56B156M020C(1)(2)125 30.0 10 125 1.2 105 15 V T56V156M020C(1)(2)100	220	D	T56D227M010C(1)(2)040	220.0	10	40	2.37	125	•
16 V _{DC} AT +105 °C; 10.7 V _{DC} AT +125 °C 22 B T56B226M016C(1)(2)070 35.2 8 70 1.36 105 33 D T56B236M016C(1)(2)070 52.8 10 70 1.63 105 33 V T56V336M016C(1)(2)070 52.8 10 70 1.63 105 47 D T56V476M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V686M016C(1)(2)070 108.8 10 70 1.63 105 100 D T56V17M016C(1)(2)050 160.0 10 50 2.12 125 • 100 V T56V17M016C(1)(2)050 160.0 10 50 1.93 105 20 V _{DC} AT +105 °C; 13.4 V _{DC} AT +125 °C 15 B T56B156M020C(1)(2)040 30.0 10 125 1.22 105	220	V	T56V227M010C(1)(2)025	220.0	10	25	2.73	105	
22 B T56B226M016C(1)(2)070 35.2 8 70 1.36 105 33 D T56D336M016C(1)(2)070 52.8 10 70 1.79 125 • 33 V T56D336M016C(1)(2)070 52.8 10 70 1.63 105 47 D T56D476M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 108.8 10 70 1.63 105 48 V T56V16M016C(1)(2)050 160.0 10 50 2.12 125 • 100 D T56D17M016C(1)(2)050 160.0 10 50 1.93 105 20 V _{DC} AT +105 °C; 13.4 V _{DC} AT +125 °C 15 B T56B156M020C(1)(2)040 44.0 10 40 2.16 105 22 V T56V36M025C(1)(2)040 <	330	D	T56D337M010C(1)(2)025	330.0	10	25	3.00	105	
33 D T56D336M016C(1)(2)070 52.8 10 70 1.79 125 • 33 V T56V336M016C(1)(2)070 52.8 10 70 1.63 105 47 D T56D476M016C(1)(2)070 75.2 10 70 1.79 125 • 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V686M016C(1)(2)070 75.2 10 70 1.63 105 100 D T56V17M016C(1)(2)050 160.0 10 50 2.12 125 • 100 V T56V17M016C(1)(2)050 160.0 10 50 1.93 105 20 V_{DC} AT +105 °C : 13.4 V_{DC} AT +125 °C 115 B T56B156M020C(1)(2)104 30.0 10 122 105 125 V T56V266M020C(1)(2)040 44.0 10 40 2.16 105 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V			16 \	V _{DC} AT +105	°C; 10.7 V _D	_C AT +125 °C	;		
33 V T56V336M016C(1)(2)070 52.8 10 70 1.63 105 47 D T56D476M016C(1)(2)070 75.2 10 70 1.63 105 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V476M016C(1)(2)070 108.8 10 70 1.63 105 100 D T56V107M016C(1)(2)050 160.0 10 50 1.2 125 • 100 V T56V107M016C(1)(2)050 160.0 10 50 1.33 105 100 V T56V107M016C(1)(2)050 160.0 10 50 1.33 105 115 B T56B156M020C(1)(2)050 80.0 10 40 2.16 105 22 V T56V266M020C(1)(2)040 44.0 10 40 2.16 105 15 B T56B156M020C(1)(2)040 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)140 37.5 10 125 1	22	В	T56B226M016C(1)(2)070	35.2	8	70	1.36	105	
47 D T56D476M016C(1)(2)070 75.2 10 70 1.79 125 • 47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V476M016C(1)(2)070 108.8 10 70 1.63 105 100 D T56D107M016C(1)(2)050 160.0 10 50 2.12 125 • 100 V T56V107M016C(1)(2)050 160.0 10 50 1.93 105 100 V T56V107M016C(1)(2)050 160.0 10 50 1.93 105 15 B T56B156M020C(1)(2)000 30.0 8 90 1.2 105 15 V T56V156M020C(1)(2)125 30.0 10 40 2.16 105 22 V T56V366M025C(1)(2)040 66.0 10 40 2.16 105 15 B T56B156M025C(1)(2)040 37.5 8 100 1.14 105 15 V T56V26M025C(1)(2)040 55.0 10 40 <td>33</td> <td>D</td> <td>T56D336M016C(1)(2)070</td> <td>52.8</td> <td>10</td> <td>70</td> <td>1.79</td> <td>125</td> <td>•</td>	33	D	T56D336M016C(1)(2)070	52.8	10	70	1.79	125	•
47 V T56V476M016C(1)(2)070 75.2 10 70 1.63 105 68 V T56V686M016C(1)(2)070 108.8 10 70 1.63 105 100 D T56D107M016C(1)(2)050 160.0 10 50 2.12 125 • 100 V T56V107M016C(1)(2)050 160.0 10 50 1.93 105 20 V_{DC} AT +105 °C; 13.4 V_{DC} AT +125 °C 20 V_{DC} AT +105 °C; 13.4 V_{DC} AT +125 °C 15 B T56B156M020C(1)(2)125 30.0 10 125 1.2 105 15 V T56V156M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V26M020C(1)(2)040 44.0 10 40 2.16 105 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)100 37.5 10 125 1.22 105 22 V T56V526M025C(1)(2)100 37.5 10 126	33	V	T56V336M016C(1)(2)070	52.8	10	70	1.63	105	
68 V T56V686M016C(1)(2)070 108.8 10 70 1.63 105 100 D T56D107M016C(1)(2)050 160.0 10 50 2.12 125 • 100 V T56D107M016C(1)(2)050 160.0 10 50 1.93 105 20 V_{DC} AT +105 °C; 13.4 V_{DC} AT +125 °C 15 B T56B156M020C(1)(2)125 30.0 8 90 1.2 105 15 V T56V156M020C(1)(2)125 30.0 10 125 1.22 105 22 V T56V266M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V36M020C(1)(2)040 66.0 10 40 2.16 105 33 V T56V156M025C(1)(2)100 37.5 8 100 1.14 105 15 B T56B156M025C(1)(2)100 37.5 10 125 1.22 105 22 V T56V156M025C(1)(2)100 37.5 10 125 1.22 105 33 D	47	D	T56D476M016C(1)(2)070	75.2	10	70	1.79	125	•
100 D T56D107M016C(1)(2)050 160.0 10 50 2.12 125 • 100 V T56V107M016C(1)(2)050 160.0 10 50 1.93 105 20 V_{DC} AT +105 °C; 13.4 V_{DC} AT +125 °C 15 B T56B156M020C(1)(2)090 30.0 8 90 1.2 105 15 V T56V156M020C(1)(2)040 44.0 10 40 2.16 105 22 V T56V36M020C(1)(2)040 66.0 10 40 2.16 105 33 V T56V36M020C(1)(2)040 66.0 10 40 2.16 105 25 V_{DC} AT +105 °C; 16.8 V_{DC} AT +125 °C 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V226M025C(1)(2)100 37.5 10 125 1.22 105 22 V T56V36M025C(1)(2)100 37.5 10 10.14 105 15 V T56V36M025C(1)(2)040 82.5 10 60 1.93 125	47	V	T56V476M016C(1)(2)070	75.2	10	70	1.63	105	
100 V T56V107M016C(1)(2)050 160.0 10 50 1.93 105 20 V _{DC} AT +105 °C; 13.4 V _{DC} AT +125 °C 15 B T56B156M020C(1)(2)090 30.0 8 90 1.2 105 15 V T56V156M020C(1)(2)125 30.0 10 125 1.22 105 22 V T56V26M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V36M020C(1)(2)040 66.0 10 40 2.16 105 25 V _{DC} AT +105 °C; 16.8 V _{DC} AT +125 °C 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D36M025C(1)(2)040 82.5 10 60 1.93 125 • 33 D T56D107M025C(1)(2)040 82.5 10 60 1.93 105	68	V	T56V686M016C(1)(2)070	108.8	10	70	1.63	105	
20 V _{DC} AT +105 °C; 13.4 V _{DC} AT +125 °C 15 B T56B156M020C(1)(2)090 30.0 8 90 1.2 105 15 V T56V156M020C(1)(2)125 30.0 10 125 1.22 105 22 V T56V226M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V336M020C(1)(2)040 66.0 10 40 2.16 105 25 V_{DC} AT +105 °C; 16.8 V_{DC} AT +125 °C 25 V_{DC} AT +105 °C; 16.8 V_{DC} AT +125 °C 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)104 55.0 10 40 2.16 105 22 V T56V226M025C(1)(2)040 82.5 10 60 1.93 125 • 33 D T56D336M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)060 250.0 10	100	D	T56D107M016C(1)(2)050	160.0	10	50	2.12	125	•
15 B T56B156M020C(1)(2)090 30.0 8 90 1.2 105 15 V T56V156M020C(1)(2)125 30.0 10 125 1.22 105 22 V T56V226M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V336M020C(1)(2)040 66.0 10 40 2.16 105 Style AT +105 °C; 16.8 Vpc AT +125 °C T56V156M025C(1)(2)100 37.5 8 100 1.14 105 15 B T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V226M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V226M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)040 82.5 10 40 2.16 105 33 V T56V36M035C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)040 85.0 8	100	V	T56V107M016C(1)(2)050	160.0	10	50	1.93	105	
15 V T56V156M020C(1)(2)125 30.0 10 125 1.22 105 22 V T56V226M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V336M020C(1)(2)040 66.0 10 40 2.16 105 Stoppe AT +105 °C; 16.8 Vpc AT +125 °C IS B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V26M025C(1)(2)040 55.0 10 40 2.16 105 23 D T56D336M025C(1)(2)040 82.5 10 60 1.93 125 • 33 D T56D107M025C(1)(2)040 82.5 10 40 2.16 105 33 V T56b107M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56B106M035C(1)(2)040 82.5 10 60 1.93 105 110 D T56			20 \	V _{DC} AT +105	°C; 13.4 V _D	_C AT +125 °C	;		
22 V T56V226M020C(1)(2)040 44.0 10 40 2.16 105 33 V T56V336M020C(1)(2)040 66.0 10 40 2.16 105 Stype AT +105 °C; 16.8 Vpc AT +125 °C 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V26M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56V336M025C(1)(2)040 82.5 10 60 1.93 125 • 33 V T56V36M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56B106M035C(1)(2)040 82.5 10 40 1.93 105 101 B T56B106M035C(1)(2)000 35.0 8 200 0.80 105 101 D T56D106M035C(1)(2	15	В	T56B156M020C(1)(2)090	30.0	8	90	1.2	105	
33 V T56V336M020C(1)(2)040 66.0 10 40 2.16 105 25 V _{DC} AT +105 °C; 16.8 V _{DC} AT +125 °C 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V26M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)040 82.5 10 60 1.93 125 • 33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 33 V T56D107M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)000 250.0 10 60 1.93 105 101 B T56B106M035C(1)(2)200 35.0	15	V	T56V156M020C(1)(2)125	30.0	10	125	1.22	105	
25 V _{DC} AT +105 °C; 16.8 V _{DC} AT +125 °C 15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V226M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)040 82.5 10 60 1.93 125 • 33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)040 82.5 10 40 2.16 105 Stype AT +105 °C; 23.5 Vpc AT +125 °C 10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)120 35.0 10 125 1	22	V	T56V226M020C(1)(2)040	44.0	10	40	2.16	105	
15 B T56B156M025C(1)(2)100 37.5 8 100 1.14 105 15 V T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V226M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)060 82.5 10 60 1.93 125 • 33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)040 82.5 10 40 2.16 105 SV T56D107M025C(1)(2)060 250.0 10 60 1.93 105 SV T56D107M025C(1)(2)060 250.0 10 60 1.93 105 SV T56D107M025C(1)(2)200 35.0 8 200 0.80 105 10 D T56B106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 120 1.36 105	33	V	T56V336M020C(1)(2)040	66.0	10	40	2.16	105	
15 V T56V156M025C(1)(2)125 37.5 10 125 1.22 105 22 V T56V226M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)060 82.5 10 60 1.93 125 • 33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)060 250.0 10 60 1.93 105 Stype AT +105 °C; 23.5 Vpc AT +125 °C 10 B T56B106M035C(1)(2)120 35.0 10 120 1.36 125 • 10 D T56V156M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 120 1.36 105 •			25	V _{DC} AT +105	°C; 16.8 V _D	_C AT +125 °C	;		
22 V T56V226M025C(1)(2)040 55.0 10 40 2.16 105 33 D T56D336M025C(1)(2)060 82.5 10 60 1.93 125 • 33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 33 V T56D107M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)060 250.0 10 60 1.93 105 SV _{DC} AT +105 °C; 23.5 V _{DC} AT +125 °C 10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 120 1.36 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 S0 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C	15	В	T56B156M025C(1)(2)100	37.5	8	100	1.14	105	
33 D T56D336M025C(1)(2)060 82.5 10 60 1.93 125 • 33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)060 250.0 10 60 1.93 105 Stype AT +105 °C; 23.5 Vpc AT +125 °C 10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 120 1.36 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 S0 Vpc AT +105 °C; 33.5 Vpc AT +125 °C	15	V		37.5	10	125	1.22	105	
33 V T56V336M025C(1)(2)040 82.5 10 40 2.16 105 100 D T56D107M025C(1)(2)060 250.0 10 60 1.93 105 SV _{DC} AT +105 °C; 23.5 V _{DC} AT +125 °C 10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 125 1.22 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 S0 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C	22	V	T56V226M025C(1)(2)040	55.0	10	40	2.16	105	
100 D T56D107M025C(1)(2)060 250.0 10 60 1.93 105 35 V_{DC} AT +105 °C; 23.5 V_{DC} AT +125 °C 10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 125 1.22 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 50 V_{DC} AT +105 °C; 33.5 V_{DC} AT +125 °C	33	D	T56D336M025C(1)(2)060	82.5	10	60	1.93	125	•
35 V _{DC} AT +105 °C; 23.5 V _{DC} AT +125 °C 10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 125 1.22 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 50 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C	33	V	T56V336M025C(1)(2)040	82.5	10	40	2.16	105	
10 B T56B106M035C(1)(2)200 35.0 8 200 0.80 105 10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 125 1.22 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 50 Vpc AT +105 °C; 33.5 Vpc AT +125 °C	100	D	T56D107M025C(1)(2)060	250.0	10	60	1.93	105	
10 D T56D106M035C(1)(2)120 35.0 10 120 1.36 125 • 15 V T56V156M035C(1)(2)125 52.5 10 125 1.22 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 50 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C				V _{DC} AT +105		_C AT +125 °C			
15 V T56V156M035C(1)(2)125 52.5 10 125 1.22 105 22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 50 Vpc AT +105 °C; 33.5 Vpc AT +125 °C	10	В	T56B106M035C(1)(2)200	35.0	8	200	0.80	105	
22 D T56D226M035C(1)(2)120 77.0 10 120 1.36 105 50 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C	10	D	T56D106M035C(1)(2)120	35.0	10	120		125	•
50 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C	15	V	T56V156M035C(1)(2)125	52.5	10	125	1.22	105	
	22	D						105	
10 D T56D106M050C(1)(2)120 50.0 10 120 1.36 105			50 \	V _{DC} AT +105	°C; 33.5 V _D	_C AT +125 °C	;		
	10	D	T56D106M050C(1)(2)120	50.0	10	120	1.36	105	

Note ٠

Part number definitions: (1) Reliability level: Z, S (2) Surge current: A, B, S

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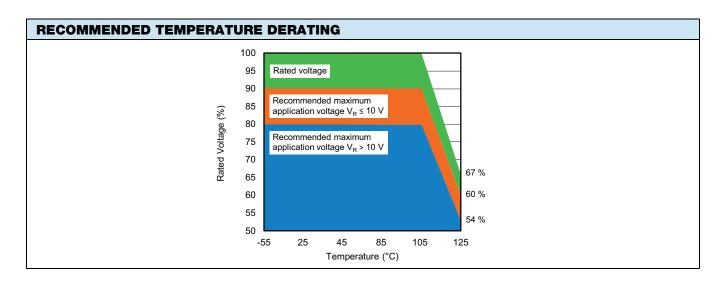
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ISHAY

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T56

RECOMMENDED VOLTAGE DERATING GUIDELINES							
CAPACITOR VOLTAGE RATING AT -55 °C TO +105 °C	CAPACITOR CATEGORY VOLTAGE AT +105 °C TO +125 °C	RECOMMENDED VOLTAGE DERATING AT -55 °C TO +105 °C	RECOMMENDED VOLTAGE DERATING AT +105 °C TO +125 °C				
2.5	1.7	2.3	1.5				
4	2.7	3.6	2.4				
6.3	4.2	5.7	3.8				
10	6.7	9	6.0				
16	10.7	12.8	8.6				
20	13.4	16	10.8				
25	16.8	20	13.5				
35	23.5	28	18.9				
50	33.5	40	27.0				



POWER DISSIPATION	
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION (W) AT \leq +45 °C IN FREE AIR
D	0.225

STANDARD PACKAGING QUANTITY			
CASE CODE UNITS PER 7" REEL			
D	500		



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PERFORMAN	CE CHARACTERISTICS		
ITEM	CONDITION	POST TEST PERFOR	MANCE
Life test	2000 h application of rated voltage at 105 $^{\circ}C$ ⁽¹⁾ ,	Capacitance change	Within ± 20 % of initial value
	2000 h application of 2/3 rated voltage at 125 °C $^{(1)}$,	Dissipation factor	Within initial limits
	MIL-STD-202 method 108	Leakage current	Shall not exceed 300 % of initial limit
Shelf life test	2000 h no voltage applied at 105 °C ⁽¹⁾ ,	Capacitance change	Within ± 20 % of initial value
	2000 h no voltage applied at 125 °C ⁽¹⁾ , MIL-STD-202 method 108	Dissipation factor	Within initial limits
	MIL-STD-202 Method 108	Leakage current	Shall not exceed 300 % of initial limit
Humidity tests	At 60 °C / 90 % RH 500 h, no voltage applied ⁽¹⁾	Capacitance change	-5 % to +50 % of initial value
	At 85 °C / 85 % RH 500 h, rated voltage applied ⁽¹⁾	Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Resistance	MIL-STD-202, method 210, condition J	Capacitance change	Within ± 20 % of initial value
to solder heat	(SnPb capacitors) and K (Pb-free capacitors)	Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Stability at low and	-55 °C	Capacitance change	Within -30 % to 0 % of initial value
high temperatures		Dissipation factor	Shall not exceed 150 % of initial limit
		Leakage current	n/a
	25 °C	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Within initial limit
	85 °C	Capacitance change	Within -50 % to +30 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 1000 % of initial value
	105 °C / 125 °C ⁽¹⁾	Capacitance change	Within 0 % to +50 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 1000 % of initial limit
Surge voltage	105 °C, 1000 successive test cycles at 1.3 of rated	Capacitance change	Within ± 20 % of initial value
	voltage in series with a 33 Ω resistor at	Dissipation factor	Within initial limit
	the rate of 30 s ON, 30 s OFF	Leakage current	Shall not exceed 300 % of initial limit
Shock	MIL-STD-202, method 213, condition I,	Capacitance change	Within \pm 20 % of initial value
(specified pulse)	100 <i>g</i> peak	Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.	
Vibration	MIL-STD-202, method 204, condition D,	Capacitance change	Within \pm 20 % of initial value
	10 Hz to 2000 Hz 20 g peak	Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
			hanical or visual damage to capacitors
Shear test	Apply a pressure load of 5 N for 10 s \pm 1 s	Capacitance change	Within \pm 20 % of initial value
	horizontally to the center of capacitor side body	Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
		Loundyo ourront	

Note

⁽¹⁾ Test temperature and test conditions, please refer to table "Standard Ratings"

PRODUCT INFORMATION				
Polymer Guide	www.vishay.com/doc?40076			
Moisture Sensitivity	www.vishay.com/doc?40135			
Infographic	www.vishay.com/doc?48084			
Sample Board	www.vishay.com/doc?48073			
FAQ				
Frequently Asked Questions	www.vishay.com/doc?42106			

Revision: 13-Dec-2023

6 For technical questions, contact: polytech@vishay.com Document Number: 40219

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Vishav

Guide for Tantalum Solid Electrolyte Chip Capacitors With Polymer Cathode

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Revision: 22-Nov-2023

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS				
DIELECTRIC	e DIELECTRIC CONSTANT			
Air or vacuum	1.0			
Paper	2.0 to 6.0			
Plastic	2.1 to 6.0			
Mineral oil	2.2 to 2.3			
Silicone oil	2.7 to 2.8			
Quartz	3.8 to 4.4			
Glass	4.8 to 8.0			
Porcelain	5.1 to 5.9			
Mica	5.4 to 8.7			
Aluminum oxide	8.4			
Tantalum pentoxide	26			
Ceramic	12 to 400K			

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

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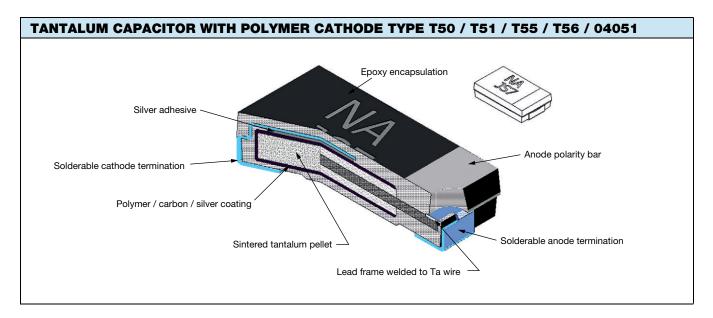


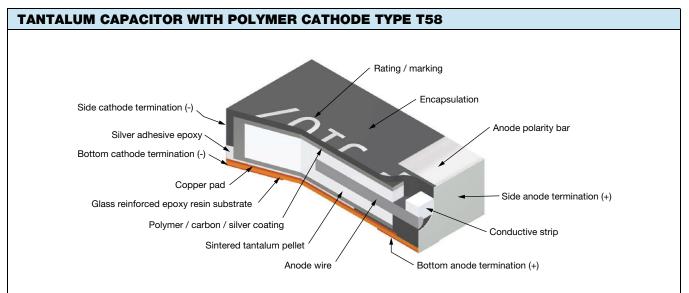
SOLID ELECTROLYTE POLYMER TANTALUM CAPACITORS

Solid electrolyte polymer capacitors utilize sintered tantalum pellets as anodes. Tantalum pentoxide dielectric layer is formed on the entire surface of anode, which is further impregnated with highly conductive polymer as cathode system.

The conductive polymer layer is then coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the capacitor element and the outer termination (lead frame or other).

Molded chip polymer tantalum capacitor encases the element in plastic resins, such as epoxy materials. The molding compound has been selected to meet the requirements of UL 94 V-0 and outgassing requirements of ASTM E-595. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for variety of applications in electronic devices. Usage of conductive polymer cathode system provides very low equivalent series resistance (ESR), which makes the capacitors particularly suitable for high frequency applications.

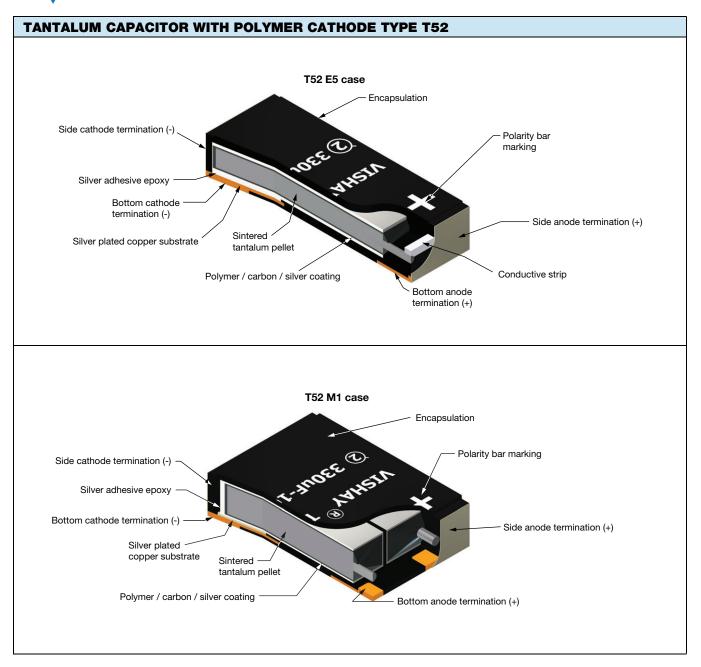






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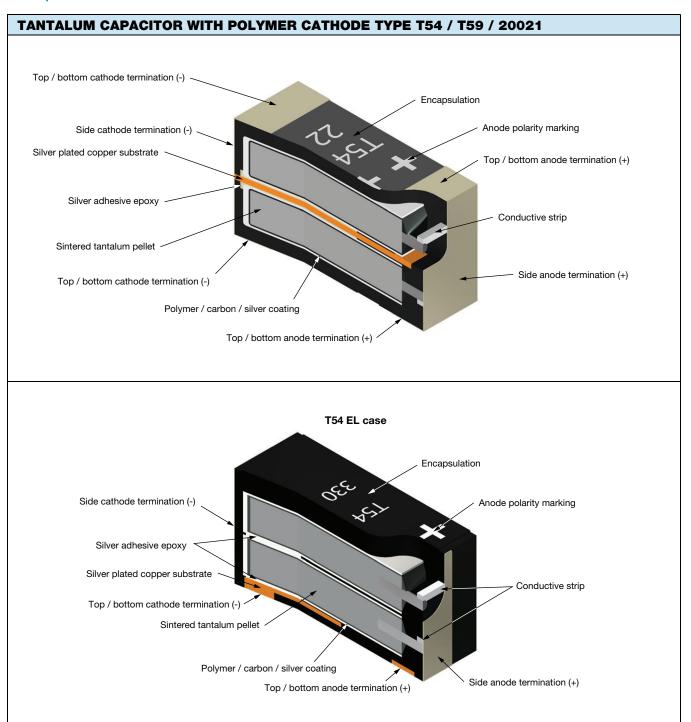


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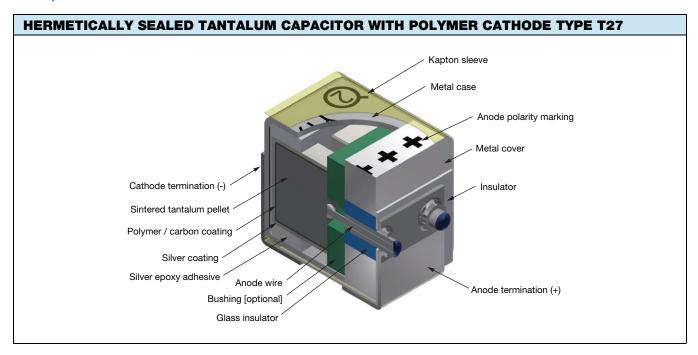
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POLYMER CAPACITORS - METAL CASE, HERMETICALLY SEALED				
SERIES	T27			
PRODUCT IMAGE				
ТҮРЕ	VPolyTan TM hermetically sealed polymer surface-mount chip capacitors, low ESR			
FEATURES	Hermetically sealed in metal case, low ESR / low DCL, hi-rel. processing			
TEMPERATURE RANGE	-55 °C to +125 °C			
CAPACITANCE RANGE	15 μF to 470 μF			
VOLTAGE RANGE	16 V to 75 V			
CAPACITANCE TOLERANCE	± 20 %			
LEAKAGE CURRENT	0.05 CV			
DISSIPATION FACTOR	12 %			
ESR	25 m Ω to 100 m Ω			
CASE SIZES	D			
TERMINATION FINISH	100 % tin; tin / lead			



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POLYMER CAPACITORS - MOLDED CASE					
SERIES	T50, T51, T55, T56	04051			
PRODUCT IMAGE	Frank Frank Frank Frank	Field With			
ТҮРЕ	VPolyTan TM , molded case, high performance polymer	VPolyTan [™] , molded case, high performance polymer			
FEATURES	High performance	High performance			
TEMPERATURE RANGE	-55 °C to +105 °C / +125 °C	-55 °C to +125 °C (above +105 °C, voltage derating is required)			
CAPACITANCE RANGE	3.3 μF to 1000 μF	4.7 μF to 680 μF			
VOLTAGE RANGE	2.5 V to 63 V	2.5 V to 63 V			
CAPACITANCE TOLERANCE	± 20 %	± 10 %, ± 20 %			
LEAKAGE CURRENT	0.1 CV	0.1 CV			
DISSIPATION FACTOR	8 % to 10 %	8 % to 10 %			
ESR	6 m Ω to 500 m Ω	$25 \text{ m}\Omega$ to $125 \text{ m}\Omega$			
CASE SIZES	J, P, A, T, B, Z, V, D, C	B, D			
TERMINATION FINISH	Cases J, P, C: 100 % tin Case A, T, B, Z, V, D: Ni / Pd / Au	All cases: tin / lead (SnPb)			

POLYMER CAPACITORS - LEADFRAMELESS MOLDED CASE						
SERIES	T52	T58	T59	T54	20021	
PRODUCT IMAGE		F.107			R R R R R R R R R R R R R R R R R R R	
ТҮРЕ	vPolyTan [™] polymer surface mount chip capacitors, low profile, leadframeless molded type	vPolyTan [™] polymer surface mount chip capacitors, compact, leadframeless molded type	vPolyTan [™] polymer surface mount chip capacitors, low ESR, leadframeless molded type	vPolyTan [™] polymer surface mount chip capacitors, low ESR, leadframeless molded type, hi-rel commercial off-the-shelf (COTS)	vPolyTan TM polymer surface mount chip capacitors, low ESR, leadframeless molded type, DLA approved	
FEATURES	Low profile	Small case size	Multianode	Hi-rel COTS, multianode	Multianode	
TEMPERATURE RANGE	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +125 °C	-55 °C to +125 °C	-55 °C to +125 °C	
CAPACITANCE RANGE	47 μF to 470 μF	1 μF to 100 μF	15 μF to 470 μF	15 μF to 470 μF (discrete capacitors) 30 μF to 2800 μF (stacked capacitors)	15 μF to 470 μF (discrete capacitors) 30 μF to 2800 μF (stacked capacitors)	
VOLTAGE RANGE	10 V to 35 V	6.3 V to 35 V	16 V to 75 V	16 V to 75 V	16 V to 75 V	
CAPACITANCE TOLERANCE	± 20 %	± 20 %	± 10 %, ± 20 %	± 20 %	± 20 %	
LEAKAGE CURRENT			0.1 CV	•		
DISSIPATION FACTOR	10 %	8 % to 14 %	10 % to 12 %	10 % to 12 %	10 % to 12 %	
ESR	40 m Ω to 200 m Ω	90 m Ω to 500 m Ω	20 m Ω to 150 m Ω	5 m Ω to 150 m Ω	5 m Ω to 150 m Ω	
CASE SIZES	E5, M1, M9, B2	MM, W0, W9, A0, BB	EE, EL	EE, EL, E2, E3, E4, E6, 3E, 6E	EE, E2, E3, E4, E6, 3E, 6E	
TERMINATION	100	% tin	100 % tin	; tin / lead	Tin / lead	

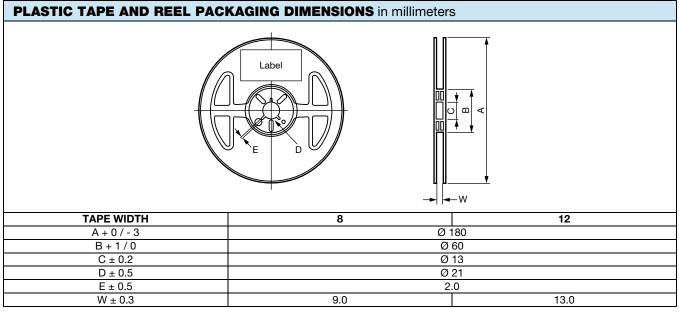
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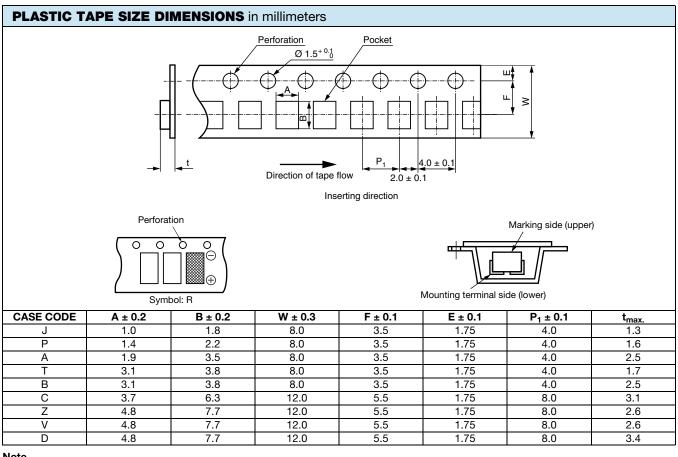


MOLDED CAPACITORS, T50 / T51 / T55 / T56 / 04051 TYPES



Note

• A reel diameter of 330 mm is also applicable



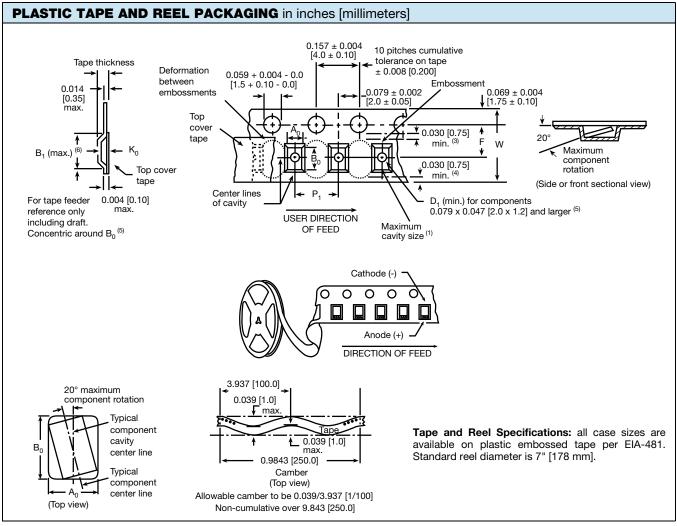
Note

A reel diameter of 330 mm is also applicable

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LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES



Notes

- · Metric dimensions will govern. Dimensions in inches are rounded and for reference only
- (1) A₀, B₀, K₀, are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀, K₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum
- ⁽³⁾ This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less
- ⁽⁵⁾ The embossed hole location shall be measured from the sprocket hole controlling the location of the embossment. Dimensions of embossment location shall be applied independent of each other
- ⁽⁶⁾ B₁ dimension is a reference dimension tape feeder clearance only



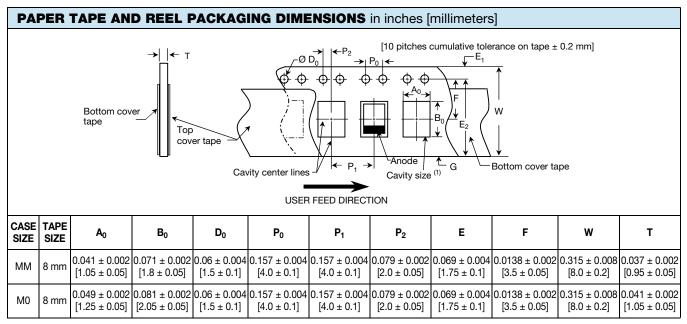
CARRIER	CARRIER TAPE DIMENSIONS in inches [millimeters]							
CASE CODE	TAPE SIZE	B ₁ (MAX.) ⁽¹⁾	D ₁ (MIN.)	F	K ₀ (MAX.)	P ₁	P ₂	w
E5	12 mm	0.329 [8.35]	0.059 [1.5]	0.217 ± 0.002 [5.50 ± 0.05]	0.071 [1.8]	$\begin{array}{c} 0.315 \pm 0.004 \\ [8.0 \pm 0.10] \end{array}$	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.476 ± 0.008 [12.1 ± 0.20]
MM ⁽²⁾	8 mm	0.075 [1.91]	0.02 [0.5]	0.138 [3.5]	0.043 [1.10]	0.157 [4.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.315 [8.0]
M1, M9	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.094 [2.39]	0.315 ± 0.04 [8.0 ± 1.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
W9	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.315 [8.0]
WO	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.315 [8.0]
A0	8 mm	-	0.02 [0.5]	0.138 [3.5]	0.049 [1.25]	0.157 [4.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.315 [8.0]
BB	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.087 [2.22]	0.157 [4.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.315 [8.0]
EE, EL	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.175 [4.44]	0.315 ± 0.04 [8.0 ±1.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
B2	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.057 [1.45]	0.157 [4.0]	$\begin{array}{c} 0.079 \pm 0.002 \\ [2.00 \pm 0.05] \end{array}$	0.315 [8.0]
D ⁽³⁾	16 mm	0.321 [8.16]	0.059 [1.5]	0.295 ± 0.004 [7.50 ± 0.1]	0.308 [7.83]	$\begin{array}{c} 0.472 \pm 0.004 \\ [12.00 \pm 0.1] \end{array}$	$\begin{array}{c} 0.079 \pm 0.004 \\ [2.00 \pm 0.1] \end{array}$	0.630 ± 0.012 [16.00 ± 0.3]

Notes

⁽¹⁾ For reference only

⁽²⁾ Standard packaging of MM case is with paper tape. Plastic tape is available per request

⁽³⁾ Tape thickness 0.018 [0.45] max.



Note

(1) A₀, B₀ are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°

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PACKING AND STORAGE

Polymer capacitors meet moisture sensitivity level rating (MSL) of 3 or 4 as specified in IPC/JEDEC[®] J-STD-020 and are dry packaged in moisture barrier bags (MBB) per J-STD-033. MSL for each particular family is defined in the datasheet - either in "Features" section or "Standard Ratings" table. Level 3 specifies a floor life (out of bag) of 168 hours and level 4 specifies a floor life of 72 hours at 30 °C maximum and 60 % relative humidity (RH). Unused capacitors should be re-sealed in the MBB with fresh desiccant. A moisture strip (humidity indicator card) is included in the bag to assure dryness. To remove excess moisture, capacitors can be dried at 40 °C (standard "dry box" conditions).

For detailed recommendations please refer to J-STD-033.

RECOMMENDED REFLOW PROFILES Vishay recommends no more than 3 cycles of reflow in accordance with J-STD-020. T Max. ramp up rate = 3 °C/s Max. ramp down rate = 6 °C/s Т Temperature T_{Smax} Preheat area 25 Time 25 °C to peak Time -**PROFILE FEATURE** SnPb EUTECTIC ASSEMBLY LEAD (Pb)-FREE ASSEMBLY PREHEAT AND SOAK Temperature min. (T_{Smin.}) 100 °C 150 °C 200 °C Temperature max. (T_{Smax.}) 150 °C Time (t_S) from (T_{Smin.} to T_{Smax.}) 60 s to 120 s 60 s to 120 s RAMP UP Ramp-up rate (T_L to T_p) 3 °C/s maximum 183 °C 217 °C Liquidus temperature (TL) Time (t_L) maintained above T 60 s to 150 s Peak package body temperature (T_p) max. Depends on type and case - see table below Time (tp) within 5 °C of the peak max. temperature 20 s 5 s (1) RAMP DOWN Ramp-down rate (T_p to T_L) 6 °C/s maximum Time from 25 °C to peak temperature 6 min maximum 8 min maximum

Note

⁽¹⁾ For T27, lead (Pb)-free capacitors $t_p = 30 \text{ s}$

PEAK PACKAGE BODY TEMPERATURE (T _p) MAXIMUM					
TYPE	CASE CODE	PEAK PACKAGE BODY 1	EMPERATURE (T _P) MAX.		
ITPE	CASE CODE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY		
T27	D	220 °C	245 °C		
T55	J, P, A, T, B, C, Z, V, D		260 °C		
T52	E5, M1, M9, B2		260 °C		
T58	MM, W9, W0, A0, BB	2/2	260 °C		
T50	D	n/a	260 °C		
T51	D, V		260 °C		
T56	B, D, V		250 °C		
T59	EE, EL	220 °C	250 °C		
T54	EL, 3E, 6E, EE, E2, E3, E4, E6	220 °C	250 °C		
20021	3E, 6E, EE, E2, E3, E4, E6	220 °C	n/a		
04051	B, D	220 °C	n/a		

Notes

T50, T51, T52, T55, T56, and T58 capacitors are process sensitive.

PSL classification to JEDEC J-STD-075: R4G

 T54 and T59 capacitors with 100 % tin termination are process sensitive. PSL classification to JEDEC J-STD-075: R6G

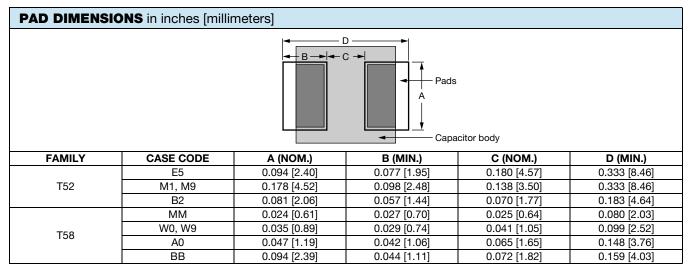
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MOLDED CAPACITORS, T50 / T51 / T55 / T56 / 04051 TYPES

PAD DIMENSIONS in millimeters							
Pattern Capacitor W Y G Z							
CASE /	CAPACI	TOR SIZE		PAD DIM	ENSIONS		
DIMENSIONS	L	W	G (max.)	Z (min.)	X (min.)	Y (Ref.)	
J	1.6	0.8	0.7	2.5	1.0	0.9	
Р	2.0	1.25	0.5	2.6	1.2	1.05	
А	3.2	1.6	1.1	3.8	1.5	1.35	
T/B	3.5	2.8	1.4	4.1	2.7	1.35	
С	5.8	3.2	2.9	6.9	2.7	2.0	
Z/V/D	7.3	4.3	4.1	8.2	2.9	2.05	

LEADFRAMELESS MOLDED CAPACITORS T52 / T58



LEADFRAMELESS MOLDED CAPACITORS T59 / T54 / 20021

D DIMENSI	ONS in inches [milli	meters]					
Pads A Capacitor body							
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)		
	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]			
TEO / TEA	EE	0.200 [0.00]	0.090 [2.30]	0.109 [4.30]	0.366 [9.30]		
T59 / T54	EL	0.098 [2.50]	0.098 [2.50]	0.169 [4.30]			
T59 / T54					0.366 [9.30		
	EL	0.098 [2.50]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30 0.394 [10.0		
T59 / T54 T54	EL E2 / E3	0.098 [2.50] 0.128 [3.24]	0.098 [2.50] 0.120 [3.04]	0.169 [4.30] 0.154 [3.92]	0.366 [9.30 0.394 [10.0 0.394 [10.0		
	EL E2 / E3 E4 / E6	0.098 [2.50] 0.128 [3.24] 0.301 [7.64]	0.098 [2.50] 0.120 [3.04] 0.120 [3.04]	0.169 [4.30] 0.154 [3.92] 0.154 [3.92]	0.366 [9.30] 0.366 [9.30] 0.394 [10.0] 0.394 [10.0] 0.394 [10.0] 0.394 [10.0]		

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HERMETICALLY SEALED CAPACITOR T27 TYPE

PAD DIMENSIONS in inches [millimeters]						
	- 					
CASE CODE	A (MIN.)	B (NOM.)	C (NOM.)	D (NOM.)		
D	0.295 [7.50]	0.138 [3.50]	0.100 [2.50]	0.374 [9.50]		

GUIDE TO APPLICATION

1. **AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

- P = power dissipation in W at +45 °C as given in the tables in the product datasheets.
- R_{ESR} = the capacitor equivalent series resistance at the specified frequency.
- 2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

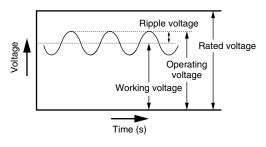
$$V_{RMS} = Z_{\sqrt{\frac{P}{R_{ESR}}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

where,

- P = power dissipation in W at +45 °C as given in the tables in the product datasheets.
- R_{ESR} = The capacitor equivalent series resistance at the specified frequency.
- Z = The capacitor impedance at the specified frequency.
- 2.1 The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



3. **Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +45 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR	
≤ 45 °C	1.0
55 °C	0.8
85 °C	0.6
105 °C	0.4
125 °C	0.25

4. **Reverse Voltage:** the capacitors are not intended for use with reverse voltage applied. However, they are capable of withstanding momentary reverse voltage peaks, which must not exceed the following values:

At 25 $^{\circ}\text{C}\text{:}$ 10 % of the rated voltage or 1 V, whichever is smaller.

At 85 °C: 5 % of the rated voltage or 0.5 V, whichever is smaller.

At 105 $^\circ\text{C:}$ 3 % of the rated voltage or 0.3 V, whichever is smaller.

5. Mounting Precautions:

5.1 **Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 3 °C per second. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see www.vishay.com/doc?40214.

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5.2 Limit Pressure on Capacitor Installation with Mounter: pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

5.3 Flux Selection

- 5.3.1 Select a flux that contains a minimum of chlorine and amine.
- 5.3.2 After flux use, the chlorine and amine in the flux remain must be removed.
- 5.4 **Cleaning After Mounting:** the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.
 - Halogen organic solvent (HCFC225, etc.)
 - Alcoholic solvent (IPA, ethanol, etc.)
 - Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout



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